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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/749,500	12/31/2003	Hitesh Windlass	42P17807 1217		
8791	7590 04/26/2005		EXAMINER		
	' SOKOLOFF TAYLOR SHIRE BOULEVARD	TRAN, MAI HUONG C			
SEVENTH			ART UNIT	PAPER NUMBER	
LOS ANGE	LES, CA 90025-1030	2818			
			DATE MAILED: 04/26/2009	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application N	lo	Applicant(s)				
Office Action Summary		10/749,500		WINDLASS ET AL.				
		Examiner		Art Unit				
		Mai-Huong Tr	an	2818				
The MAILING D	PATE of this communication app	ears on the co	ver sheet with the c	orrespondence addr	'ess			
A SHORTENED STATTHE MAILING DATE Extensions of time may be a after SIX (6) MONTHS from If the period for reply specific If NO period for reply is spece Failure to reply within the set	TUTORY PERIOD FOR REPLY OF THIS COMMUNICATION: vailable under the provisions of 37 CFR 1.13 the mailing date of this communication. ed above is less than thirty (30) days, a reply ified above, the maximum statutory period w or extended period for reply will, by statute, fice later than three months after the mailing ent. See 37 CFR 1.704(b).	36(a). In no event, h y within the statutory vill apply and will exp , cause the applicati	nowever, may a reply be tim minimum of thirty (30) days oire SIX (6) MONTHS from on to become ABANDONED	ely filed s will be considered timely. the mailing date of this com O (35 U.S.C. § 133).	munication.			
Status								
2a)☐ This action is FI 3)☐ Since this applic	This action is FINAL . 2b)⊠ This action is non-final.							
Disposition of Claims								
4a) Of the above 5)⊠ Claim(s) <u>7-14</u> is 6)⊠ Claim(s) <u>1-6</u> is/a 7)□ Claim(s)	Claim(s) 1-24 is/are pending in the application. 4a) Of the above claim(s) 15-24 is/are withdrawn from consideration. Claim(s) 7-14 is/are allowed. Claim(s) 1-6 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or election requirement.							
Application Papers								
10)⊠ The drawing(s) f Applicant may no Replacement dra	n is objected to by the Examiner iled on 31 December 2003 is/and trequest that any objection to the owing sheet(s) including the correction aration is objected to by the Examiner.	ire: a)⊠ acce drawing(s) be h tion is required i	eld in abeyance. Seef the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFF	R 1.121(d).			
Priority under 35 U.S.C.	§ 119							
a) All b) Sor 1. Certified (2. Certified (3. Copies of application)	It is made of a claim for foreign ne * c) None of: copies of the priority documents copies of the priority documents the certified copies of the prior n from the International Bureau detailed Office action for a list of	s have been ro s have been ro rity documents u (PCT Rule 1	eceived. eceived in Application have been receive 7.2(a)).	on No ed in this National S	tage			
	Patent Drawing Review (PTO-948) atement(s) (PTO-1449 or PTO/SB/08)	5)	Interview Summary Paper No(s)/Mail Da Notice of Informal P Other:		152)			

DETAILED ACTION

Election/Restriction

Application's election without traverse of Group II (claims 1-14) drawn to process of making a semiconductor device is acknowledged for prosecution in the subject application. Accordingly, claims 15-24 are withdrawn from consideration as being directed to a non-elected invention. See 37 CFR 1.142(b) and MPEP § 821.03.

Applicants have the right to file a divisional application covering the subject matter of the non-elected claims.

Claim Rejections - 35 U.S.C. § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1 and 5-6 are rejected under 35 U.S.C. 103 (a) as being unpatentable over U.S. Patent No. 6,812,509 to Xu in view of US Publication No. 2004/0209420 to Ljungcrantz et al. and further in view of Gudesen et al. (6,878,980).

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Regarding to claim 1, Xu discloses a method comprising placing a substrate 10 with a ferroelectric polymer layer 14 formed thereon and sputtering (col. 4, lines 18-19) a metal layer 18, 20, 52 on the ferroelectric polymer layer (col. 9, lines 52-54), (col. 9, lines 33-38, col. 10, lines 48-51) (figs. 2, 5, 8).

Xu does not disclose placing a substrate with a ferroelectric polymer layer formed thereon in a chamber. However, Ljungcrantz discloses the substrate with the ferroelectric polymer layer formed thereon in a chamber (page 2, [0013]).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to form a substrate with a ferroelectric polymer layer formed thereon in a chamber, as taught by Ljungcrantz in order to provide a high-purity evaporation source in an effusion cell (page 2, [0013]).

Xu also does not disclose sputtering a metal layer at a reduced flux on the ferroelectric polymer layer. However, Gudesen discloses forming a metal layer at a reduced flux (col. 14, lines 48-49).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to sputter a metal layer at a reduced flux, as taught by Gudesen in order to improve fatigue resistance (col. 1, line 12).

Regarding to claim 5, Xu discloses the method wherein sputtering comprises forming a metal layer of at least one of TiN, TaN, TiNSi, and TaNSi (col. 4, lines 41-45).

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Regarding to claim 6, Xu in view of Ljungcrantz and Gudesen discloses the claimed invention except for the method wherein sputtering comprises sputtering with an ion gun.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to sputter with an ion gun.

Claims 2-4 are rejected under 35 U.S.C. 103 (a) as being unpatentable over U.S. Patent No. 6,812,509 to Xu in view of US Publication No. 2004/0209420 to Ljungcrantz and Gudesen et al. (6,878,980) and further in view of Chiang et al. (6582569)

Regarding to claim 2, Xu in view of Ljungcrantz et al., and Gudesen et al. discloses the claimed invention except for the method wherein sputtering comprises sputtering in the presence of a collimator. Chiang discloses the method wherein sputtering comprises sputtering in the presence of a collimator (col. 3, lines 22-29).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to sputter in the presence of a collimator, as taught by Chiang in order to provide electrical connections between large number of active semiconductor devices (col. 1, lines 16-18).

Regarding to claim 3, Chiang discloses the method wherein sputtering may be performed at a pressure less than approximately 10 milliTorr (col. 16, lines 20-24).

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Regarding to claim 4, Chiang discloses the method wherein sputtering may be performed at a pressure equal to or less than approximately 2.5 milliTorr (col. 16, lines 20-24).

Allowable Subject Matter

Claims 7-14 are allowed.

Conclusion

Any inquiry concerning this communication on earlier communications from the examiner should be directed to Mai-Huong Tran, (571) 272-1796. The examiner can normally be reached on Monday-Thursday from 8:00 AM to 6:30 PM. The examiner's supervisor, David Nelms can be reached on (571) 272-1787.

The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR, Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Mai-Huong Tran